

High-Bandwidth, Low Voltage, Dual SPDT Analog Switch

FEATURES

• Single Supply (1.8 V to 5.5 V)

- Low On-Resistance $r_{ON:}$ 2.4 Ω
- Crosstalk and Off Isolation: -81 dB @ 1 MHz
- QFN-12 (3 x 3 mm) Package

BENEFITS

- Reduced Power Consumption
- High Accuracy
- Reduce Board Space
- Low-Voltage Logic Compatible
- High Bandwidth

APPLICATIONS

- Cellular Phones
- Speaker Headset Switching
- Audio and Video Signal Routing
- PCMCIA Cards
- Low-Voltage Data Acquisition
- ATE

DESCRIPTION

The DG2032 is a monolithic CMOS dual single-pole/ double-throw (SPDT) analog switch. It is specifically designed for low-voltage, high bandwidth applications.

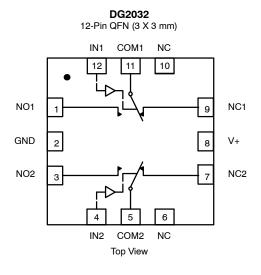
The DG2032's on-resistance (3 Ω @ 2.7 V), matching and flatness are guaranteed over the entire analog voltage range. Wide dynamic performance is achieved with better than –80 dB for both cross-talk and off-isolation at 1 MHz.

Both SPDT's operate with independent control logic, conduct equally well in both directions and block signals up to the power supply level when off. Break-before-make is guaranteed.

With fast switching speeds, low on-resistance, high bandwidth, and low charge injection, the DG2032 is ideally suited for audio and video switching with high linearity.

Built on Vishay Siliconix's low voltage CMOS technology, the DG2032 contains an epitaxial layer which prevents latch-up.

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



TRUTH TABLE					
Logic	NO1 and NO2				
0	ON	OFF			
1	OFF	ON			

ORDERING INFORMATION						
Temp Range	Package	Part Number				
-40 to 85°C	12-Pin QFN (3 x 3 mm)	DG2032DN				

Vishay Siliconix

New Product



ABSOLUTE MAXIMUM RATINGS

Reference to GND

V+
IN, COM, NC, NO ^a
Continuous Current (Any terminal) ±50 mA
Peak Current ±200 mA
(Pulsed at 1 ms, 10% duty cycle)
Storage Temperature (D Suffix)
Power Dissipation (Packages) ^b
12-Pin QFN (3 x 3) ^c 1295 mW
Package Solder Reflow Conditions ^d
12-Pin QFN (3 x 3)

Notes:

- Signals on NC, NO, or COM or IN exceeding V+ will be clamped by intera.
- b.
- Signals on NC, NO, or COM or IN exceeding V+ will be clamped by inter nal diodes. Limit forward diode current to maximum current ratings. All leads welded or soldered to PC Board. Derate 16.2 mW/°C above 70°C Manual soldering with an iron is not recommended for leadless compo-nents. The QFN is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper lip cannot be guar-anteed and is not required to ensure adequate bottom side solder inter-connection c. d. connection.

Parameter		Test ConditionsOtherwise Unless Specified $V_{+} = 3 V$, $\pm 10\%$, $V_{IN} = 0.4$ or 2.0 Ve	Temp ^a	Limits -40 to 85°C			
	Symbol			Min ^b	Тур ^с	Max ^b	Unit
Analog Switch		•					
Analog Signal Range ^d	V _{NO} , V _{NC} , V _{COM}		Full	0		V+	V
On-Resistance	r _{ON}	V+ = 2.7 V, V _{COM} = 0.2 V/1.5 V I _{NO} , I _{NC} = 10 mA	Room Full		3.0	5 6.5	Ω
r _{ON} Flatness	r _{ON} Flatness	$V+=2.7 V \label{eq:V+} V_{COM}=0 \text{ to } V+, I_{NO}, I_{NC}=10 \text{ mA}$	Room			1.6	
r _{ON} Match Between Channels	Δr _{ON}		Room			0.4	
Switch Off Leakage Current	I _{NO(off)} , I _{NC(off)}	$V_{+} = 3.3 \text{ V}, \text{ V}_{\text{NO}}, \text{ V}_{\text{NC}} = 0.3 \text{ V/3 V}$ $\text{V}_{\text{COM}} = 3 \text{ V/0.3 V}$ $\text{V}_{+} = 3.3 \text{ V}, \text{ V}_{\text{NO}}, \text{ V}_{\text{NC}} = \text{V}_{\text{COM}} = 0.3 \text{ V/3 V}$	Room Full	-1 -10	0.01	1 10	nA
	I _{COM(off)}		Room Full	-1 -10	0.01	1 10	
Channel-On Leakage Current	I _{COM(on)}		Room Full	-1 -10	0.01	1 10	
Digital Control			-			•	
Input High Voltage	V _{INH}		Full	2.0			v
Input Low Voltage	V _{INL}		Full			0.4	v
Input Capacitance	C _{in}		Full		5		pF
Input Current	I _{INL} or I _{INH}	V _{IN} = 0 or V+	Full	1		1	μΑ
Dynamic Characteristics			-			•	
Turn-On Time	t _{ON}	V_{NO} or V_{NC} = 2.0 V, R_L = 50 Ω,C_L = 35 pF	Room Full		28	53 59	ns
Turn-Off Time	tOFF		Room Full		13	38 38	
Break-Before-Make Time	t _d	$V_{NO} \text{ or } V_{NC}$ = 2.0 V, R_L = 50 Ω, C_L = 35 pF	Full	1			
Charge Injection ^d	Q _{INJ}	C_L = 1 nF, V_{GEN} = 0 V, R_{GEN} = 0 Ω	Room		38		рС
Off-Isolation ^d	OIRR	R_L = 50 Ω , C_L = 5 pF, f = 1 MHz	Room		-78		dB
Crosstalk ^d	X _{TALK}		Room		-82		
$N_O, N_C Off Capacitance^d$	C _{NO(off)}		Room		15		– pF
	C _{NC(off)}		Room		15		
Channel-On Capacitanced	C _{NO(on)}		Room		49		
	C _{NC(on)}		Room		45		
Power Supply							
Power Supply Current	I+	V _{IN} = 0 or V+	Full		0.01	1.0	μA
		•			•		

Notes:

Room = 25° C, Full = as determined by the operating suffix. a.

Typical values are for design aid only, not guaranteed nor subject to production testing. b.

The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet. c.

Guarantee by design, nor subjected to production test. V_{IN} = input voltage to perform proper function. d.

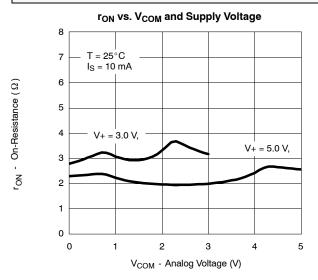
e.

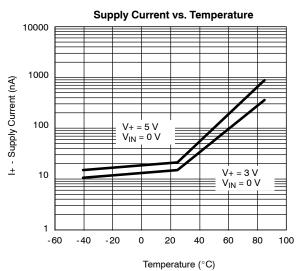


New Product

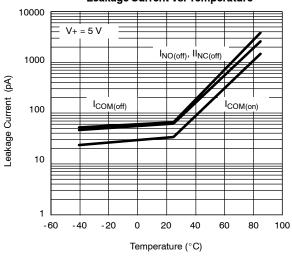
DG2032 Vishay Siliconix

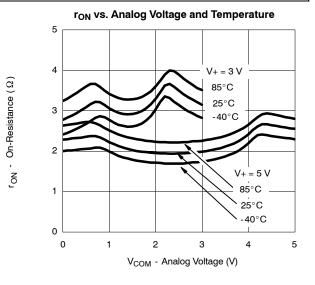
TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)



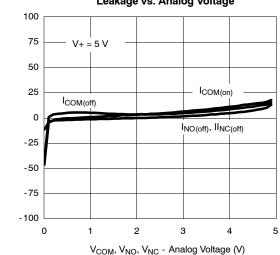


Leakage Current vs. Temperature





Supply Current vs. Input Switching Frequency 10 mA V+ = 5 V `₩ 1 mA I+ - Supply Current (A) ++++++++++ 1++++ 100 μA 10 μA 1 μΑ Ŧ₩ -----------100 nA 10 nA 10 100 1 K 10 K 100 K 1 M 10 M Input Switching Frequency (Hz)



Leakage Current (pA)

Leakage vs. Analog Voltage

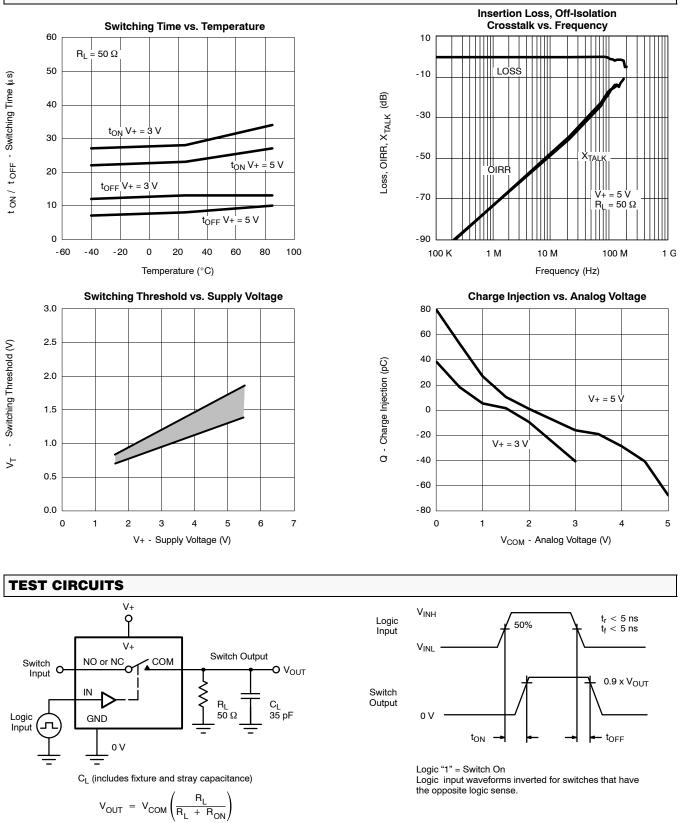
DG2032

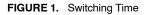
Vishay Siliconix

New Product



TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)





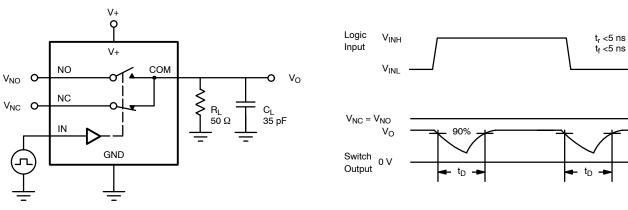


DG2032

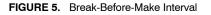
New Product

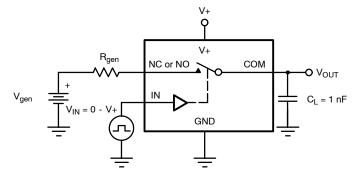
Vishay Siliconix

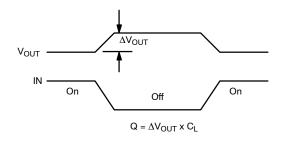
TEST CIRCUITS



CL (includes fixture and stray capacitance)







IN depends on switch configuration: input polarity determined by sense of switch.



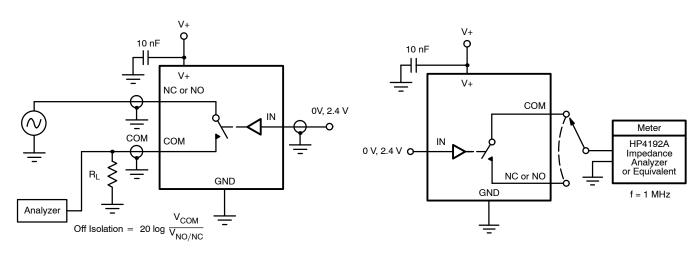


FIGURE 3. Off-Isolation

FIGURE 4. Channel Off/On Capacitance



Vishay

Disclaimer

All product specifications and data are subject to change without notice.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained herein or in any other disclosure relating to any product.

Vishay disclaims any and all liability arising out of the use or application of any product described herein or of any information provided herein to the maximum extent permitted by law. The product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein, which apply to these products.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications unless otherwise expressly indicated. Customers using or selling Vishay products not expressly indicated for use in such applications do so entirely at their own risk and agree to fully indemnify Vishay for any damages arising or resulting from such use or sale. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

Product names and markings noted herein may be trademarks of their respective owners.